Diode Semiconductor Device - Page 1 of 1



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la de sues Material.	
Inclosure Material:	
Metal	
Overall Length:	
0.610 inches	
Overall Diameter:	
0.165 inches	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
5.0 reverse voltage, peak	
Current Rating Per Characteristic:	
10.00 milliamperes forward current, average absolute	
Maximum Operating Tempurature Per Measurement Point:	
300.0 degrees celsius junction	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	